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Renesas Technology Corp. Customer Support Dept. April 1, 2003



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Octal Buffers/Line Drivers/Line Receivers (with noninverted 3-state outputs)

RENESAS

ADE-205-551 (Z) 1st. Edition Sep. 2000

Description

The HD74HCT241 is a noninverting buffer and has one active low enable and one active high enable. Each enable independently controls 4 buffers.

This device does not have schmitt trigger inputs.

Features

- LSTTL Output Logic Level Compatibility as well as CMOS Output Compatibility
- High Speed Operation: t_{pd} (A to Y) = 10 ns typ ($C_L = 50 \text{ pF}$)
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 4.5$ to 5.5 V
- Low Input Current: 1 µA max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)

Function Table

Inputs			Output
1 G	2G	Α	Y
Н	L	Х	Z
L	Н	Н	Н
L	Н	L	L

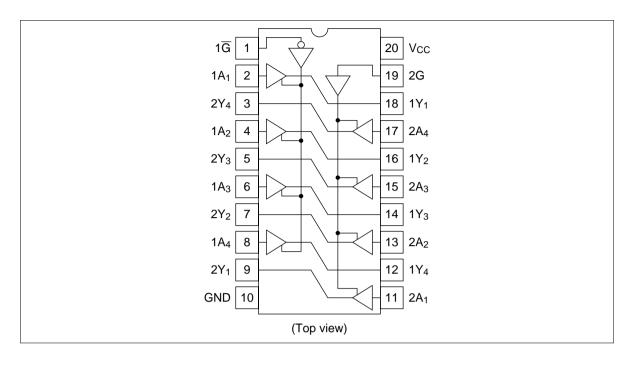
H : High level

L : Low level

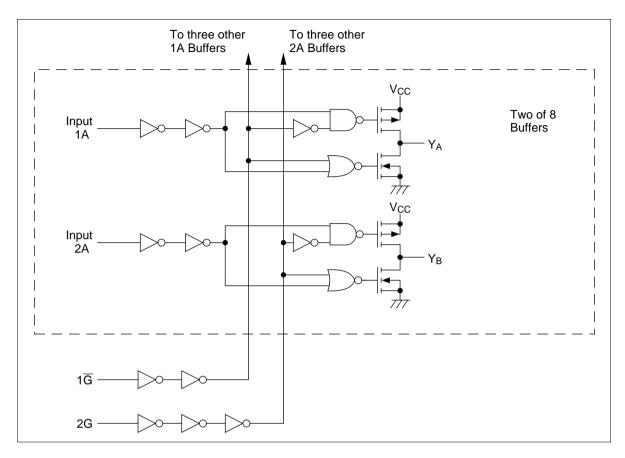
X : Irrelevant

Z : Off (high impedance) state of a 3-state output

Pin Arrangement



Block Diagram



Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage range	V _{cc}	-0.5 to +7.0	V
Input voltage	V _{IN}	–0.5 to V _{cc} + 0.5	V
Output voltage	V _{OUT}	-0.5 to V_{cc} + 0.5	V
DC current drain per pin	I _{out}	±35	mA
DC current drain per V_{cc} , GND	$I_{\rm CC}, I_{\rm GND}$	±75	mA
DC input diode current	I _{IK}	±20	mA
DC output diode current	Ι _{οκ}	±20	mA
Power dissipation per package	P _T	500	mW
Storage temperature	Tstg	–65 to +150	°C



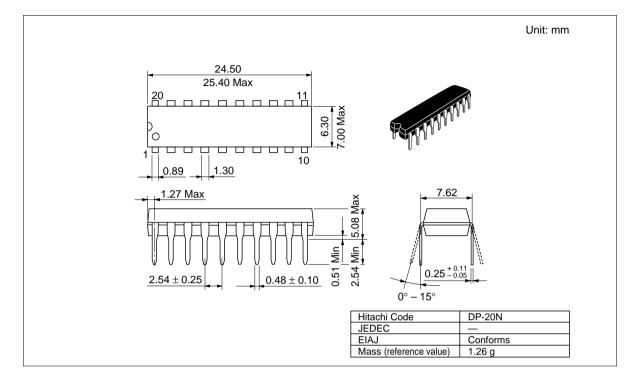
DC Characteristics

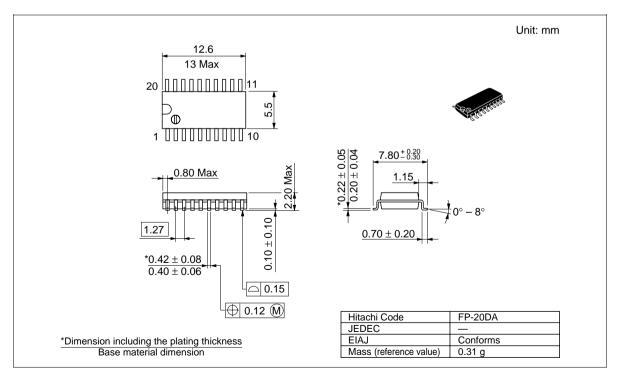
		Ta =	= 25°C	;	Ta = ∙ +85°0	–40 to C		Test Co	onditions
Item	Symbol	Min	Тур	Max	Min	Max	Unit	V _{cc} (V)	-
Input voltage	V _{IH}	2.0	_	_	2.0	—	V	4.5 to 5.5	
	V _{IL}	—	—	0.8	_	0.8	V	4.5 to 5.5	
Output voltage	V _{OH}	4.4	_		4.4	—	V	4.5	Vin = V_{IH} or V_{IL} \ I_{OH} = -20 \ \mu A
		4.18	-	—	4.13	—		4.5	I _{он} = —6 mА
	V _{OL}	—	—	0.1	_	0.1	V	4.5	Vin = V_{IH} or V_{IL} \ I_{OL} = 20 μA
_		_	—	0.26	_	0.33	_	4.5	$I_{OL} = 6 \text{ mA}$
Off-state output current	I _{oz}	—	—	±0.5	—	±5.0	μA	5.5	$Vin = V_{IH} \text{ or } V_{IL},$ Vout = V _{CC} or GND
Input current	lin		_	±0.1		±1.0	μA	5.5	$Vin = V_{cc} \text{ or } GND$
Quiescent current	I _{cc}		_	4.0		40	μΑ	5.5	Vin = V_{cc} or GND, lout = 0 μ A

AC Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

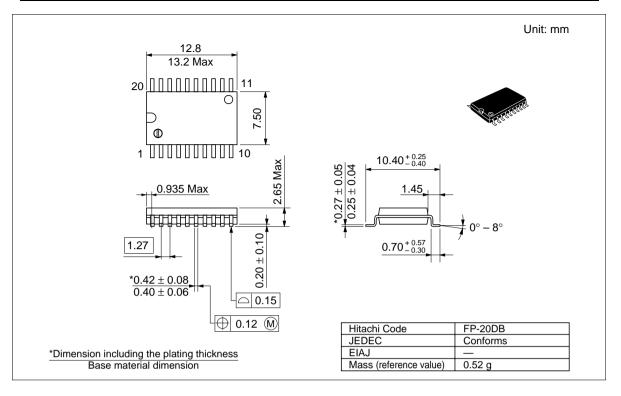
		Ta =	25°C	;	Ta = +85°(–40 to C		Test Conditions
ltem	Symbol	Min	Тур	Max	Min	Max	Unit	V _{cc} (V)
Propagation delay	t _{PHL}		11	20	_	25	ns	4.5
time	t _{PLH}		9	20	—	25	_	4.5
Output enable	t _{zL}	_	14	30	_	38	ns	4.5
time	t _{zH}	_	12	30	_	38	_	4.5
Output disable	t _{LZ}	_	13	30	_	38	ns	4.5
time	t _{HZ}	_	17	30	_	38	_	4.5
Output rise/fall time	t _{TLH} t _{THL}	_	4	12	_	15	ns	4.5
Input capacitance	Cin	_	5	10		10	pF	_

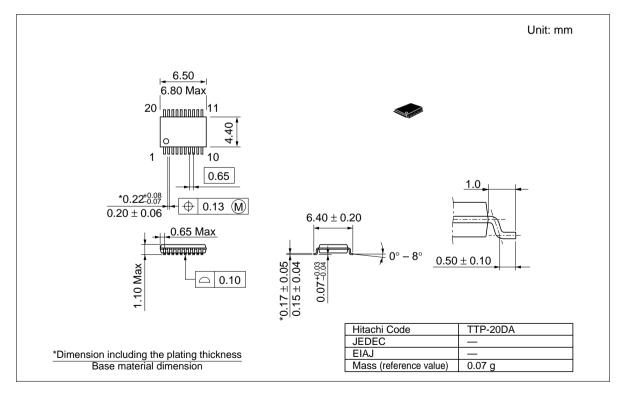
Package Dimensions





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